

Vishay Siliconix

# **CMOS Analog Switches**

### **DESCRIPTION**

The DG300B, DG303B family of monolithic CMOS switches feature three switch configuration options (SPST, SPDT, and DPST) for precision applications in communications, instrumentation and process control, where low leakage switching combined with low power consumption are required.

Designed on the Vishay Siliconix PLUS-40 CMOS process, these switches are latch-up proof, and are designed to block up to 30 V peak-to-peak when off. An epitaxial laver prevents latchup.

In the on condition the switches conduct equally well in both directions (with no offset voltage) and minimize error conditions with their low on-resistance.

Featuring low power consumption (3.5 mW typ.) these switches are ideal for battery powered applications, without sacrificing switching speed. Designed for break-before-make switching action, these devices are CMOS and quasi TTL compatible. Single supply operation is allowed by connecting the V- rail to 0 V.

### **FEATURES**

- Analog signal range: ± 15 V
- Fast switching t<sub>on</sub>: 150 ns
- Low on-resistance  $R_{DS(on)}$ : 30  $\Omega$
- Single supply operation
- · Latch-up proof
- CMOS compatible
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### Note

This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

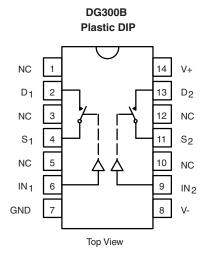
### APPLICATIONS

- · Low level switching circuits
- Programmable gain amplifiers
- Portable and battery powered systems

### **BENEFITS**

- Full rail-to-rail analog signal range
- Low signal error
- Low power dissipation

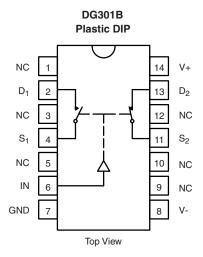
### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE	
LOGIC	SWITCH
0	Off
1	On

#### Note

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V



TRUTH TABLE		
LOGIC	SW <sub>1</sub>	SW <sub>2</sub>
0	Off	On
1	On	Off

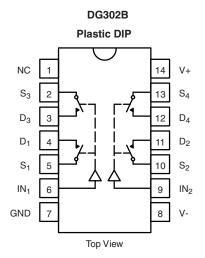
#### Note

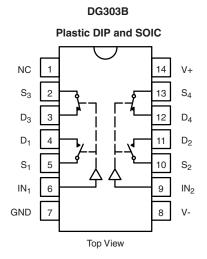
Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V



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### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**





TRUTH TABLE	
LOGIC	SWITCH
0	Off
1	On

TRUTH TABLE					
LOGIC	SW <sub>1</sub> , SW <sub>2</sub>	SW <sub>3</sub> , SW <sub>4</sub>			
0	Off	On			
1	On	Off			

### Note

• Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V

#### Note

• Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V

ORDERING INFORMATION		
TEMP. RANGE	STANDARD PACKAGE	PART NUMBER
-40 °C to +85 °C	14-SOIC	DG303BDY-E3 DG303BDY-T1-E3

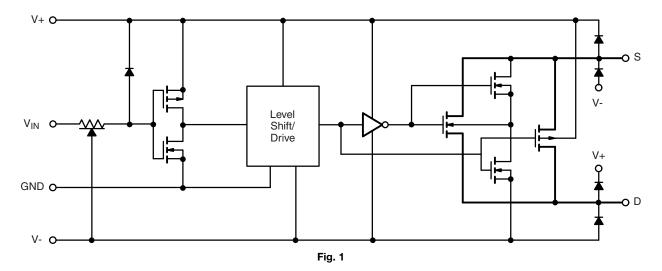
ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
PARAMETER		LIMIT	UNIT		
Voltages referenced V+ to V-		44			
GND		25	V		
Digital inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first			
Current (any terminal)		30	A		
Continuous current, S or D (pulsed	at 1 ms, 10 % duty cycle max.)	100	mA mA		
Storage temperature		-65 to +150	°C		
Power dissipation (package) b	14-pin plastic DIP <sup>c</sup>	470	mW		
rower dissipation (package)	SOIC-14 <sup>d</sup>	600	IIIVV		

### **Notes**

- a. Signals on S<sub>X</sub>, D<sub>X</sub>, or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 6.5 mW/°C above 25 °C
- d. Derate 7.6 mW/°C above 75 °C

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### **SCHEMATIC DIAGRAM** (typical channel)



SPECIFICATIONS <sup>a</sup>								
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V+ = 15 \text{ V, V-} = -15 \text{ V}$ $V_{\text{IN}} = 0.8 \text{ V OR V}_{\text{IN}} = 4 \text{ V }^{\text{f}}$		FIED TEMP.B	LIMITS -40 °C TO +85 °C			UNIT
					MIN. d	TYP. °	MAX.d	
Analog Switch								
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>			Full	-15	1	15	V
Drain-source on-resistance	R <sub>DS(on)</sub>	$V_D = \pm 10 \text{ V, I}_S =$	-10 mA	Room	-	30	50	Ω
Diani-source on-resistance	TIDS(on)	VD = ± 10 V, 1S =	-10111/	Full	-	-	75	52
Source off leakage current	I <sub>S(off)</sub>			Room	-5	± 0.1	5	
Source on leakage current	IS(off)	$V_S = \pm 14 \text{ V}, V_D =$	- ± 14 V	Hot	-100	-	100	
Drain off leakage current	la	VS = ± 14 V, VD =	- ± 14 V	Room	-5	± 0.1	5	nA
Drain on leakage current	I <sub>D(off)</sub>			Hot	-100	1	100	II/A
Drain on leakage current	la.	VS = VD = ±	14.1/	Room	-5	± 0.1	5	
Diain on leakage current	I <sub>D(on)</sub>	V3 = VD = ±	14 V	Hot	-100	ı	100	
Digital Control								
		V <sub>IN</sub> = 5		Room	-1	-0.001	-	
Input current with input voltage	$I_{\text{INH}} = 15 \text{ V}$ $V_{\text{IN}} = 15 \text{ V}$	VIN – 3 V		Full	-	ı	-	- μA
high		/	Room	-	0.001	1		
		VIN = 13 V	,	Full	-	-	-	μΛ
Input current with input voltage	I <sub>INL</sub>	V <sub>IN</sub> = 0 V		Room	-1	-0.001	-	
low	INL	V IN - 0 V		Full	-	-	-	
Dynamic Characteristics								
Turn-on time	t <sub>on</sub>	See Fig. 2		Room	-	150	-	
Turn-off time	t <sub>off</sub>	See 1 lg. 2	_	Room	-	130	-	ns
Break-before-make time	t <sub>OPEN</sub>	DG301B, DG303B	only, Fig. 3	Room	-	50	-	
Charge injection	Q	$C_L = 1 \text{ nF}, R_{gen} = 0 \Omega, V_g$	<sub>gen</sub> = 0 V, Fig. 4	Room	-	8	-	рС
Source off capacitance	C <sub>S(off)</sub>			Room	-	14	-	
Drain off capacitance	C <sub>D(off)</sub>	$V_{S}$ , $V_{D} = 0 V$ , $f = 1 MHz$		Room	-	14	-	
Channel-on capacitance	C <sub>D(on)</sub>			Room	-	40	-	pF
Input capacitance	C <sub>IN</sub>		$V_{IN} = 0 V$	Room	-	6	-	
при сараспансе	OIN	1 – 1 1011 12	V <sub>IN</sub> = 15 V	Room	-	7	-	
Off isolation	OIRR	$V_{IN} = 0 \text{ V}, R_L = 1 \text{ k}\Omega,$		Room	-	62	-	dB
Crosstalk (channel-to-channel)	X <sub>TALK</sub>	f = 500 kHz		Room	-	74	-	QD

# DG300B, DG301B, DG302B, DG303B

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SPECIFICATIONS a							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.B	LIMITS -40 °C TO +85 °C			UNIT
. /	01111202	V+ = 15 V, V- = -15 V V <sub>IN</sub> = 0.8 V OR V <sub>IN</sub> = 4 V <sup>f</sup>		MIN. d	TYP. c	MAX.d	
Power Supplies							
Positive supply current	L.	I+ V <sub>IN</sub> = 4 V (one input)	Room	-	0.23	1	mA
	1+		Full	-	-	-	IIIA
Negative supply current	I-	all others = 0 V	Room	-100	-0.001	-	
Negative supply current	-		Full	-	=.	-	
Positivo supply current	l+		Room	-	0.001	100	
Positive supply current	1+		Full	-	-	-	μA
Negative supply current	I-	V <sub>IN</sub> = 0.8 V (all inputs)	Room	-100	-0.001	=	
	-		Full	-	-	-	1

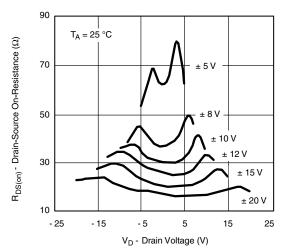
#### **Notes**

- a. Refer to PROCESS OPTION FLOWCHART
- b. Room = 25 °C, full = as determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f.  $V_{IN}$  = input voltage to perform proper function

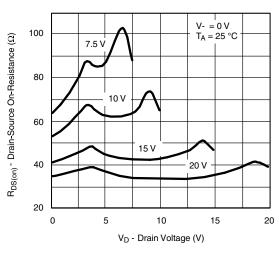
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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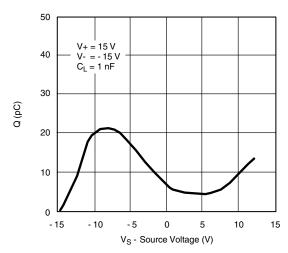
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



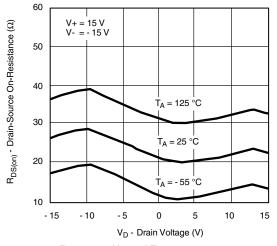
 $R_{DS(on)}$  vs.  $V_D$  and Power Supply



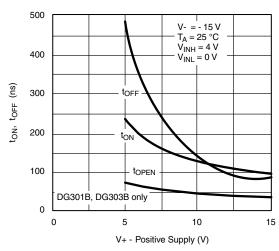
R<sub>DS(on)</sub> vs. V<sub>D</sub> and Power Supply Voltage



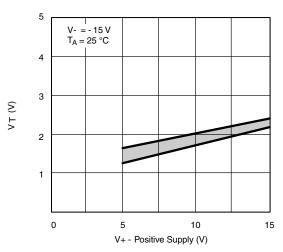
Charge Injection vs. Analog Voltage



 $R_{DS(on)} \, \nu s. \, V_D$  and Temperature



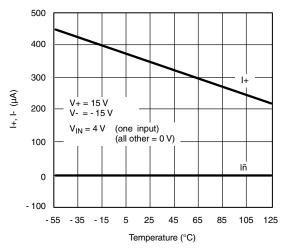
Switching Time and Break-Before-Make Time vs. Positive Supply Voltage



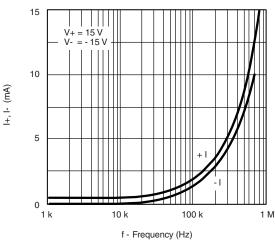
Input Switching Threshold vs. Positive Supply Voltage

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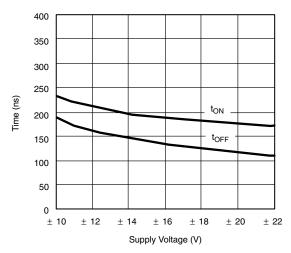
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



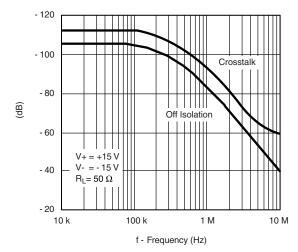
### Supply Current vs. Temperature



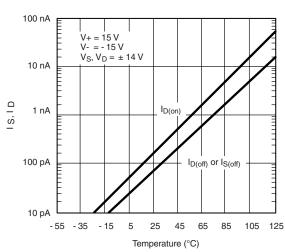
**Supply Current vs. Switching Frequency** 



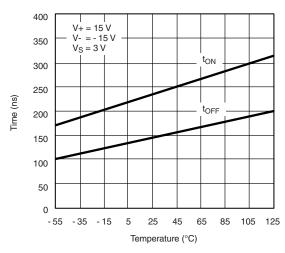
Switching Time vs. Power Supply Voltage



Off Isolation and Crosstalk vs. Frequency



Leakage vs. Temperature



Switching Time vs. Temperature

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### **TEST CIRCUITS**

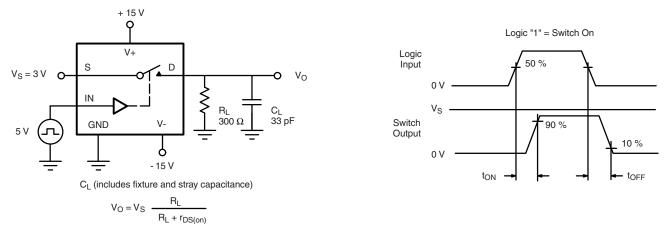


Fig. 2 - Switching Time

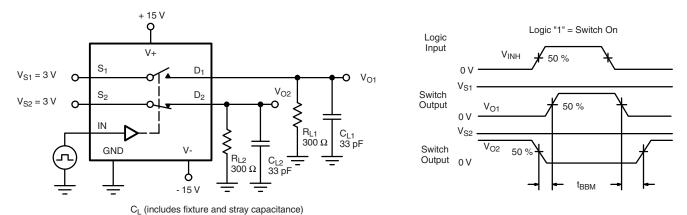


Fig. 3 - Break-Before-Make SPDT (DG301B, DG303B)

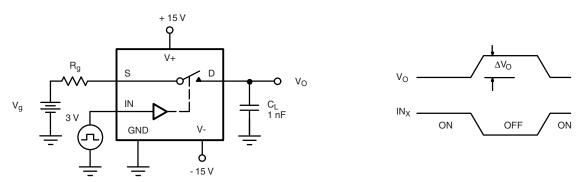


Fig. 4 - Charge Injection

APPLICATIONS HINTS <sup>a</sup>					
V+ POSITIVE SUPPLY VOLTAGE (V)	V- NEGATIVE SUPPLY VOLTAGE (V)	GND VOLTAGE (V)	V <sub>IN</sub> LOGIC INPUT VOLTAGE V <sub>INH(MIN.)</sub> /V <sub>INL(MAX.)</sub> (V)	V <sub>S</sub> OR V <sub>D</sub> ANALOG VOLTAGE RANGE (V)	
15	-15	0	4/0.8	-15 to 15	
20	-20	0	4/0.8	-20 to 20	
15	0	0	4/0.8	0 to 15	

#### Note

a. Application hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing

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### **APPLICATIONS**

The DG300B series of analog switches will switch positive analog signals while using a single positive supply. This facilitates their use in applications where only one supply is available. The trade-offs of using single supplies are:

- 1. Increased R<sub>DS(on)</sub>
- 2. Slower switching speed. The analog voltage should not go above or below the supply voltages which in single operation are V+ and 0 V. (See "Input Switching Threshold vs. Positive Supply Voltage Curve")

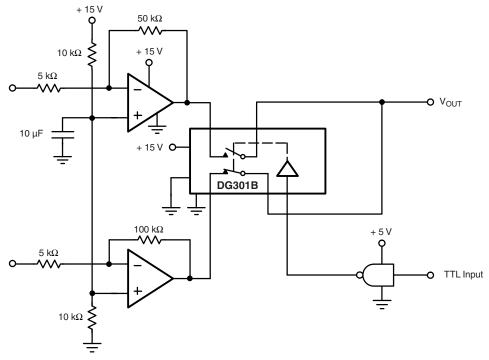


Fig. 5 - Single Supply Op. Amp. Switching

### **APPLICATIONS**

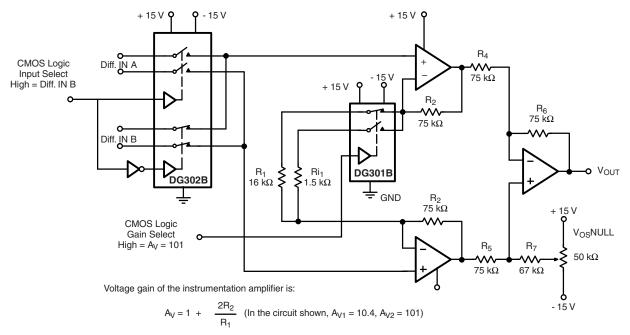


Fig. 6 - Low Power Instrumentation Amplifier with Digitally Selectable Inputs and Gain





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PRODUCT SUMMARY					
Part number	DG300B	DG301B	DG302B	DG303B	DG303B
Status code	2	2	2	2	2
Configuration	SPST x 2, NO	DPST, comp	DPST x 2, NO	DPST x 2, comp	DPST x 2, comp
Single supply min. (V)	5	5	5	5	5
Single supply max. (V)	36	36	36	36	36
Dual supply min. (V)	5	5	5	5	5
Dual supply max. (V)	22	22	22	22	22
On-resistance (Ω)	15	15	15	15	15
Charge injection (pC)	8	8	8	8	8
Source on capacitance (pF)	40	40	40	40	40
Source off capacitance (pF)	14	14	14	14	14
Leakage switch on typ. (nA)	0.1	0.1	0.1	0.1	0.1
Leakage switch off max. (nA)	5	5	5	5	5
-3 dB bandwidth (MHz)	-	-	-	-	-
Package	Plastic DIP-14	Plastic DIP-14	Plastic DIP-14	Plastic DIP-14	SO-14 (narrow) AS
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare				
Interface	Parallel	Parallel	Parallel	Parallel	Parallel
Single supply operation	Yes	Yes	Yes	Yes	Yes
Dual supply operation	Yes	Yes	Yes	Yes	Yes
Turn on time max. (ns)	150	150	150	150	150
Crosstalk and off isolation	-62	-62	-62	-62	-62

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